N-Channel 40-V (D-S) MOSFET

Key Features:

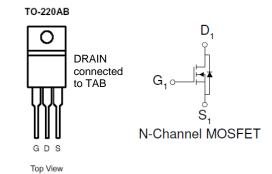
- Low r_{DS(on)} trench technology
- · Low thermal impedance
- · Fast switching speed

Typical Applications:

- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V _{DS} (V)	$r_{DS(on)}(m\Omega)$	I _D (A)	
40	4 @ V _{GS} = 10V	202	
	$6 @ V_{GS} = 4.5V$	202	





ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}$ C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Limit	Units		
Drain-Source Voltage			40	V		
Gate-Source Voltage		V_{GS}	±20	[
Continuous Drain Current ^a	T _A =25°C	I _D	202	А		
Pulsed Drain Current ^b		I _{DM}	808			
Continuous Source Current (Diode Conduction) a			202	Α		
Power Dissipation ^a	T _A =25°C	P_{D}	300	W		
Operating Junction and Storage Temperature Range			-55 to 150	°C		

THERMAL RESISTANCE RATINGS			
Parameter	Symbol	Maximum	Units
Maximum Junction-to-Ambient ^a	$R_{\theta JA}$	62.5	°C/W
Maximum Junction-to-Case	$R_{\theta JC}$	0.5	C/VV

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

Electrical Characteristics

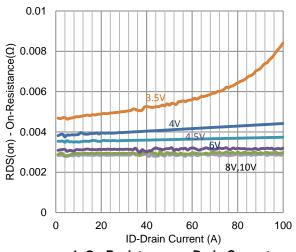
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 250 \text{ uA}$	1			V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}$			1	uA	
Zero Gate Voltage Brain Gunerit	I _{DSS}	$V_{DS} = 32 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			25		
On-State Drain Current	I _{D(on)}	$V_{DS} = 5 \text{ V}, V_{GS} = 10 \text{ V}$	120			Α	
Drain-Source On-Resistance	r	$V_{GS} = 10 \text{ V}, I_{D} = 30 \text{ A}$			4	mΩ	
	r _{DS(on)}	$V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$			6		
Forward Transconductance	g _{fs}	$V_{DS} = 15 \text{ V}, I_{D} = 30 \text{ A}$		30		S	
Diode Forward Voltage	V_{SD}	$I_{S} = 50 \text{ A}, V_{GS} = 0 \text{ V}$		1.1		V	
Dynamic							
Total Gate Charge	Q_g	$V_{DS} = 20 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 20 \text{ A}$		64		nC	
Gate-Source Charge	Q_gs			16			
Gate-Drain Charge	Q_gd			33			
Turn-On Delay Time	t _{d(on)}			22			
Rise Time	t _r	$V_{DS} = 20 \text{ V}, R_L = 1 \Omega, I_D = 20 \text{ A},$		36		ne	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = 10 \text{ V}, R_{GEN} = 6 \Omega$		209		ns	
Fall Time	t _f			86			
Input Capacitance	C _{iss}			8060			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		808		pF	
Reverse Transfer Capacitance	C_{rss}			783			

Notes

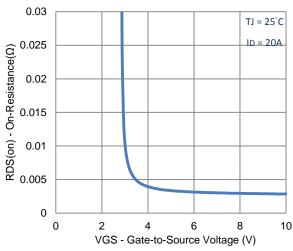
- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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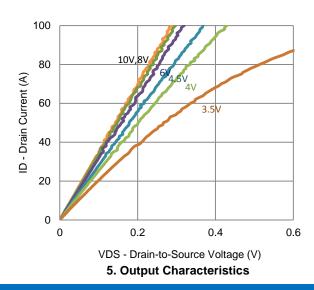
Typical Electrical Characteristics



1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage



100

TJ = 25°C

80

(4)

100

TJ = 25°C

80

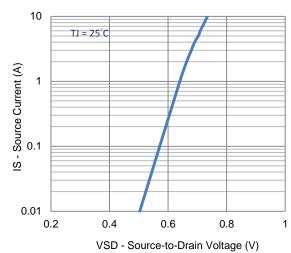
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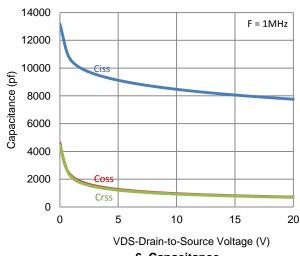
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VGS - Gate-to-Source Voltage (V)

2. Transfer Characteristics

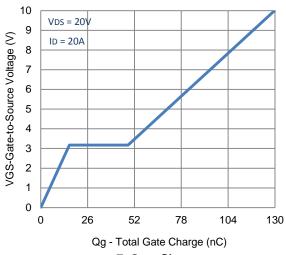


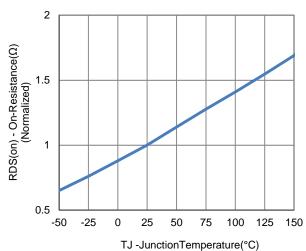
4. Drain-to-Source Forward Voltage



6. Capacitance

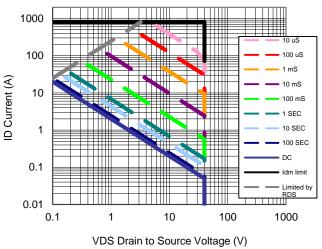
Typical Electrical Characteristics

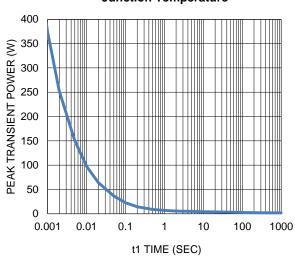






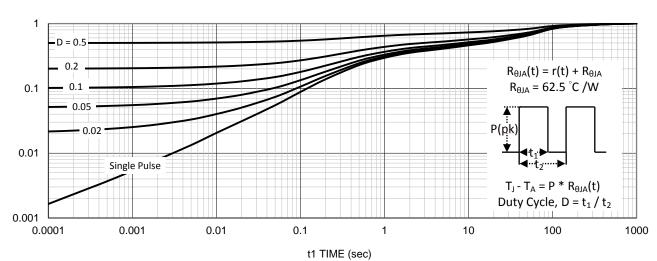






9. Safe Operating Area

10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

Package Information

